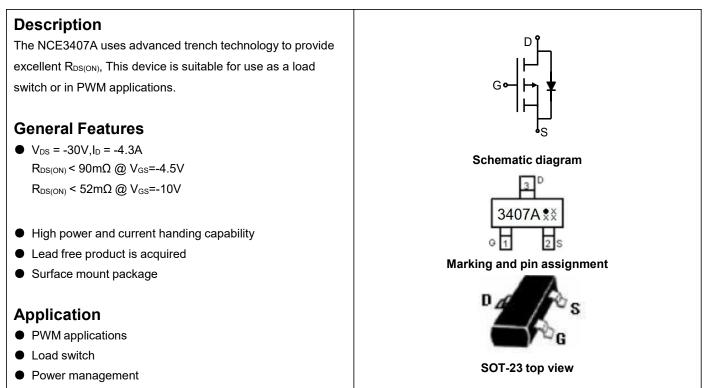


NCE P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

U	0	0			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3407A **	NCE3407A	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	ID	-4.3	A
Drain Current-Pulsed (Note 1)	Ідм	-20	A
Maximum Power Dissipation	PD	1.5	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	Reja	84	°C /W

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-	-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-24V,V _{GS} =0V	-	-	-1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250µA	-1.1	-1.5	-2.1	V
	R _{DS(ON)}	V _{GS} =-10V, I _D =-4.1A	-	42	52	mΩ
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-4A	-	50	90	mΩ
Gate resistance	Rg	V _{DS} =0V,V _{GS} =0V,F=1.0MHz	-	6	-	Ω
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-4.1A	5.5	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	Clss		-	700	-	PF
Output Capacitance	Coss	V_{DS} =-15V, V_{GS} =0V,	-	120	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	75	-	PF
Switching Characteristics (Note 4)	ł		•			
Turn-on Delay Time	t _{d(on)}		-	9	-	nS
Turn-on Rise Time	tr	V _{DD} =-15V,RL=3.6Ω	-	5	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _{GEN} =3Ω	-	28	-	nS
Turn-Off Fall Time	t _f	-	-	13.5	-	nS
Total Gate Charge	Qg		-	14	-	nC
Gate-Source Charge	Qgs	V _{DS} =-15V,I _D =-4A,V _{GS} =-10V	-	3.1	-	nC
Gate-Drain Charge	Q _{gd}	-	-	3	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	Vsd	V _{GS} =0V,I _S =-4.3A	-	-	-1.2	V
Diode Forward Current ^(Note 2)	ls		-	-	-4.3	А
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =-4.3A	-	11.5	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	5.5	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec. **3.** Pulse Test: Pulse Width $\le 300 \mu$ s, Duty Cycle $\le 2\%$.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

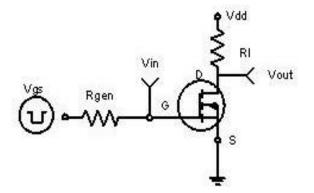
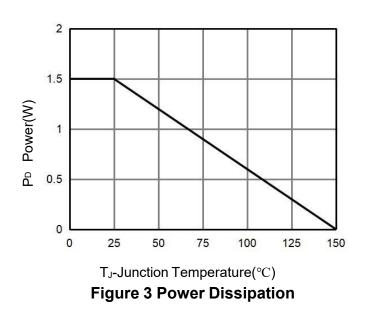
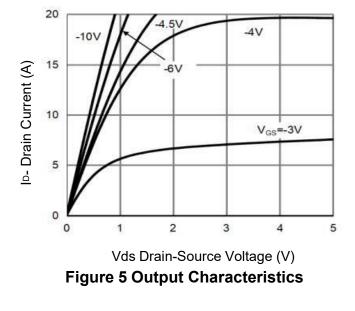


Figure 1:Switching Test Circuit





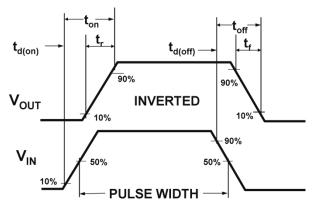
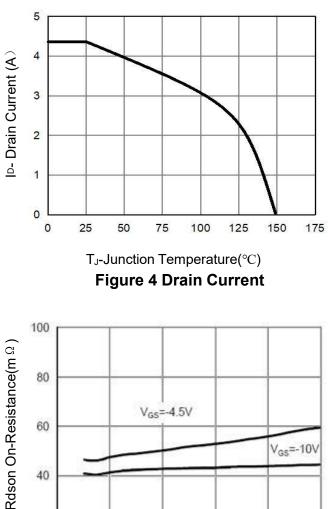


Figure 2:Switching Waveforms



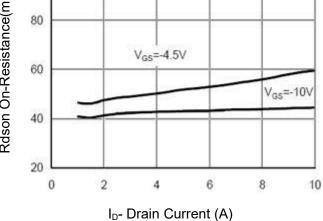
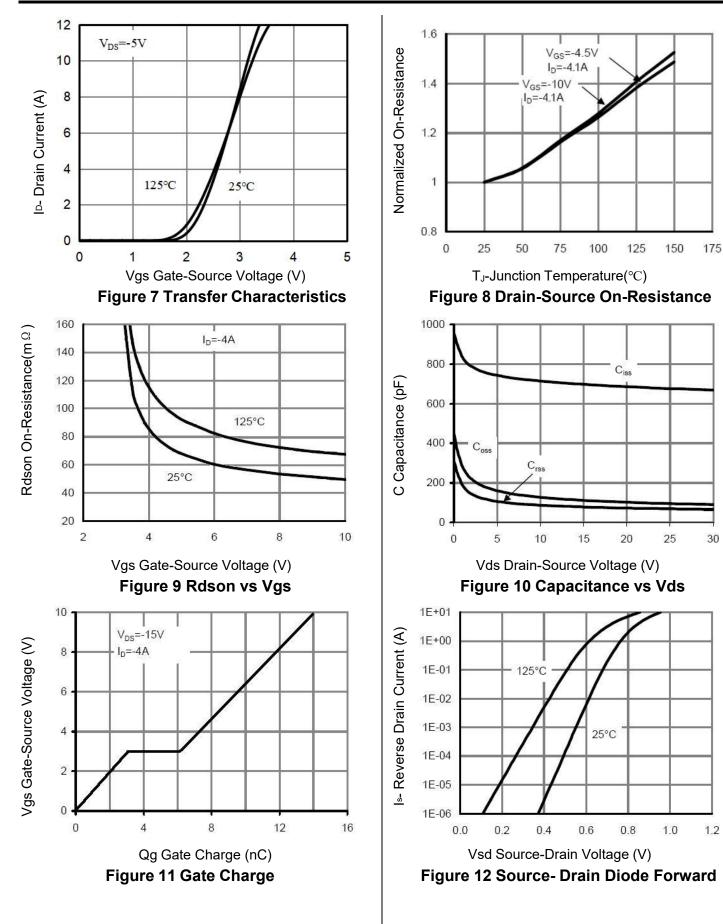


Figure 6 Drain-Source On-Resistance



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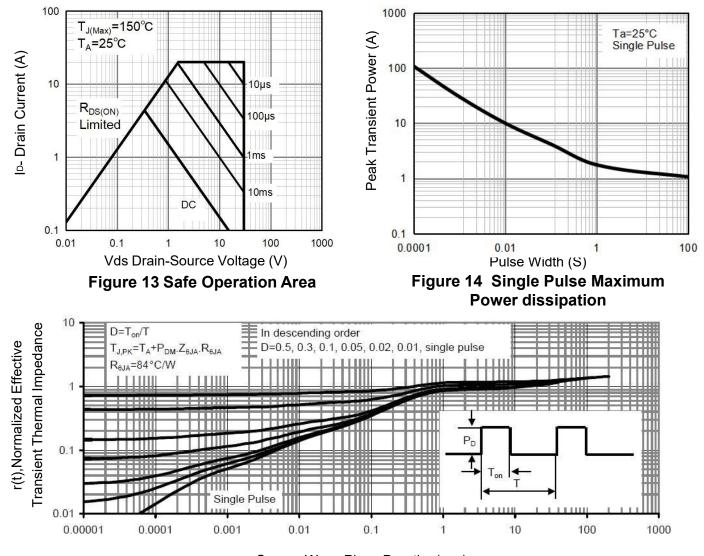
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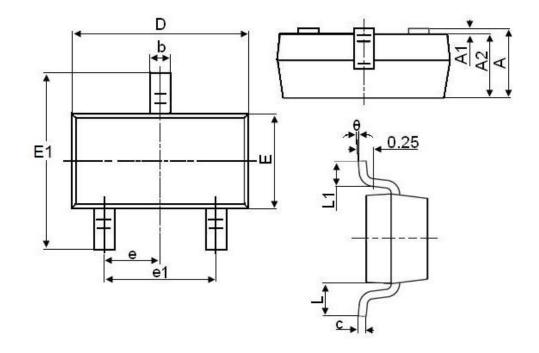
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Square Wave Pluse Duration(sec) Figure 15 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Information



Symbol	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
A	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
с	0.080	0.150			
D	2.800	3.000			
E	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L	0.550REF				
L1	0.300	0.500			
θ	0°	8°			

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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